Product Preview

Low-Voltage CMOS Octal Latching Transceiver

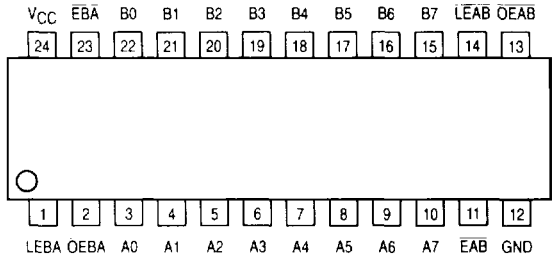
With 5V-Tolerant Inputs and Outputs (3-State, Non-Inverting)

The MC74LCX543 is a high performance, non–inverting octal latching transceiver operating from a 2.7 to 3.6V supply. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A V_I specification of 5.5V allows MC74LCX543 inputs to be safely driven from 5V devices. The MC74LCX543 is suitable for memory address driving and all TTL level bus oriented transceiver applications.

For data flow from A to B with the $\overline{EAB}$ LOW, the A–to–B Output Enable ($\overline{OEAB}$) must be LOW in order to enable data to the B bus, as indicated in the Function Table. With $\overline{EAB}$ LOW, a LOW signal on the A–to–B Latch Enable ($\overline{LEAB}$) input makes the A–to–B latches transparent; a subsequent LOW–to–HIGH transition of the $\overline{LEAB}$ signal will latch the A latches, and the outputs no longer change with the A inputs. With $\overline{EAB}$ and $\overline{OEAB}$ both LOW, the 3–State B output buffers are active and reflect the data present at the output of the A latches. Control of data flow from B to A is symetric to that above, but uses the $\overline{EBA}$, $\overline{LEBA}$, and $\overline{OEBA}$ inputs.

- Designed for 2.7 to 3.6V V_{CC} Operation
- 5V Tolerant — Interface Capability With 5V TTL Logic
- Supports Live Insertion and Withdrawal
- I_{OFF} Specification Guarantees High Impedance When V_{CC} = 0V
- LVTTL Compatible
- LVCMOS Compatible
- 24mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current in All Three Logic States (10μA) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500mA
- ESD Performance: Human Body Model >2000V; Machine Model >200V

Pinout: 24–Lead Package (Top View)



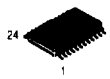
MC74LCX543

LCX

LOW–VOLTAGE CMOS OCTAL LATCHING TRANSCEIVER

DW SUFFIX
PLASTIC SOIC
CASE 751E–04

SD SUFFIX
PLASTIC SSOP
CASE 940D–03



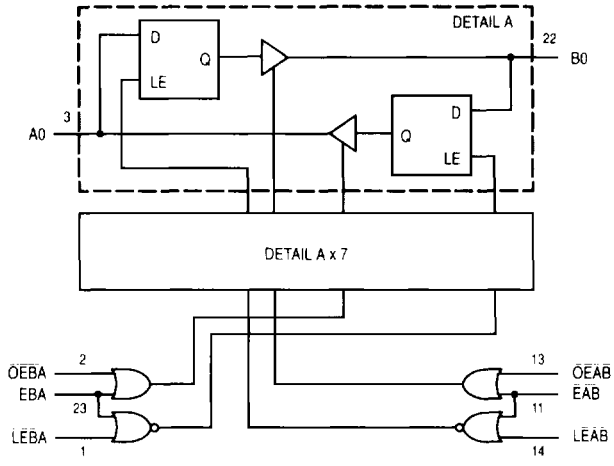
DT SUFFIX
PLASTIC TSSOP
CASE 948H–01

PIN NAMES

Pins	Function
$\overline{OEx}x$	Output Enable Inputs
$\overline{E}xx$	Enable Inputs
$\overline{L}Exx$	Latch Enable Inputs
A0–A7	3–State Inputs/Outputs
B0–B7	3–State Inputs/Outputs

This document contains information on a product under development. Motorola reserves the right to change or discontinue this product without notice.

LOGIC DIAGRAM



FUNCTION TABLE

Inputs								Internal Latch		Outputs		
An	$\overline{OEAB}$	EAB	LEAB	Bn	$\overline{OEBA}$	EBA	$\overline{LEBA}$	QABn	QBAn	A0–A7	B0–B7	Operating Mode
h	L	L	↑	U	H	X	X	H	X	NA	H	Latch & Display
l	L	L	↑	U	H	X	X	L	X	NA	L	B Outputs
X	L	L	H	U	H	X	X	NC	X	NA	NC	Hold, Read B Outputs
h	L	↑	L	X	H	X	X	H	H	NA	Z	Latch and B
l	L	↑	L	X	H	X	X	L	L	NA	Z	Outputs Disabled
h	H	L	↑	X	H	X	X	H	X	NA	Z	
l	H	L	↑	X	H	X	X	L	X	NA	Z	
H	L	L	L	U	H	X	X	H	X	NA	H	Transparent
L	L	L	L	U	H	X	X	L	X	NA	L	A to B
X	H	X	X	X	H	X	X	X	X	NA	Z	Disable B Outputs
X	X	H	X	X	H	X	X	NC	X	NA	Z	
U	H	X	X	h	L	L	↑	X	H	H	NA	Latch & Display
U	H	X	X	l	L	L	↑	X	L	L	NA	A Outputs
U	H	X	X	X	L	L	H	X	NC	NC	NA	Hold, Read A Outputs
X	H	X	X	h	L	↑	L	H	H	Z	NA	Latch and A
X	H	X	X	l	L	↑	L	L	L	Z	NA	Outputs Disabled
X	H	X	X	h	H	L	↑	X	H	Z	NA	
X	H	X	X	l	H	L	↑	X	L	Z	NA	
U	H	X	X	X	L	L	L	X	H	H	NA	Transparent
U	H	X	X	L	L	L	L	X	L	L	NA	B to A
X	H	X	X	X	H	X	X	X	X	Z	NA	Enable A Outputs
X	H	X	X	X	X	H	X	X	NC	Z	NA	

H = High Voltage Level; h = High Voltage Level One Setup Time Prior to the Latch Enable or Enable Low-to-High Transition; L = Low Voltage Level; l = Low Voltage Level One Setup Time Prior to the Latch Enable or Enable Low-to-High Transition; Z = High Impedance State; X = High or Low Voltage Level and Transitions are Acceptable; NC = No Change; ↑ = Low-to-High Transition; U = Undriven

ABSOLUTE MAXIMUM RATINGS*

Symbol	Parameter	Value	Condition	Unit
V_{CC}	DC Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	$-0.5 \le V_I \le +7.0$		V
V_O	DC Output Voltage	$-0.5 \le V_O \le +7.0$	Output in 3–State	V
		$-0.5 \le V_O \le V_{CC} + 0.5$[1]	Output in HIGH or LOW State	V
I_{IK}	DC Input Diode Current	−50	$V_I < GND$	mA
I_{OK}	DC Output Diode Current	−50	$V_O < GND$	mA
		+50	$V_O > V_{CC}$	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current Per Supply Pin	±100		mA
I_{GND}	DC Ground Current Per Ground Pin	±100		mA
T_{STG}	Storage Temperature Range	−65 to +150		°C

* Absolute maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute–maximum–rated conditions is not implied.

1. I_O absolute maximum rating must be observed.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Typ	Max	Unit
V_{CC}	Supply Voltage	Operating Data Retention Only	2.0 1.5	3.3 3.3	3.6 3.6	V
V_I	Input Voltage		0		5.5	V
V_O	Output Voltage	(HIGH or LOW State) (3–State)	0 0		V_{CC} 5.5	V
I_{OH}	HIGH Level Output Current, V_{CC} = 3.0V – 3.6V				−24	mA
I_{OL}	LOW Level Output Current, V_{CC} = 3.0V – 3.6V				24	mA
I_{OH}	HIGH Level Output Current, V_{CC} = 2.7V – 3.0V				−12	mA
I_{OL}	LOW Level Output Current, V_{CC} = 2.7V – 3.0V				12	mA
T_A	Operating Free–Air Temperature		−40		+85	°C
$\Delta t/\Delta V$	Input Transition Rise or Fall Rate, V_{IN} from 0.8V to 2.0V, V_{CC} = 3.0V		0		10	ns/V

DC ELECTRICAL CHARACTERISTICS

Symbol	Characteristic	Condition	T_A = −40°C to +85°C		Unit
			Min	Max	
V_{IH}	HIGH Level Input Voltage (Note 1)	$2.7V \le V_{CC} \le 3.6V$	2.0		V
V_{IL}	LOW Level Input Voltage (Note 1)	$2.7V \le V_{CC} \le 3.6V$		0.8	V
V_{OH}	HIGH Level Output Voltage	$2.7V \le V_{CC} \le 3.6V$; I_{OH} = −100μA	V_{CC} − 0.2		V
		V_{CC} = 2.7V; I_{OH} = −12mA	2.2		
		V_{CC} = 3.0V; I_{OH} = −18mA	2.4		
		V_{CC} = 3.0V; I_{OH} = −24mA	2.2		
V_{OL}	LOW Level Output Voltage	$2.7V \le V_{CC} \le 3.6V$; I_{OL} = 100μA		0.2	V
		V_{CC} = 2.7V; I_{OL} = 12mA		0.4	
		V_{CC} = 3.0V; I_{OL} = 16mA		0.4	
		V_{CC} = 3.0V; I_{OL} = 24mA		0.55	

1. These values of V_I are used to test DC electrical characteristics only. Functional test should use $V_{IH} \ge 2.4V$, $V_{IL} \le 0.5V$.

DC ELECTRICAL CHARACTERISTICS (continued)

Symbol	Characteristic	Condition	T_A = –40°C to +85°C		Unit
			Min	Max	
I_I	Input Leakage Current	2.7V ≤ V_{CC} ≤ 3.6V; 0V ≤ V_I ≤ 5.5V		±5.0	μA
I_{OZ}	3–State Output Current	2.7 ≤ V_{CC} ≤ 3.6V; 0V ≤ V_O ≤ 5.5V; V_I = V_{IH} or V_{IL}		±5.0	μA
I_{OFF}	Power–Off Leakage Current	V_{CC} = 0V; V_I or V_O = 5.5V		10	μA
I_{CC}	Quiescent Supply Current	2.7 ≤ V_{CC} ≤ 3.6V; V_I = GND or V_{CC}		10	μA
		2.7 ≤ V_{CC} ≤ 3.6V; 3.6 ≤ V_I or V_O ≤ 5.5V		±10	μA
ΔI_{CC}	Increase in I_{CC} per Input	2.7 ≤ V_{CC} ≤ 3.6V; V_{IH} = V_{CC} – 0.6V		500	μA

AC CHARACTERISTICS[1] (t_R = t_F = 2.5ns; C_L = 50pF; R_L = 500Ω)

Symbol	Parameter	Waveform	Limits				Unit
			T_A = –40°C to +85°C				
			V_{CC} = 3.0V to 3.6V		V_{CC} = 2.7V		
			Min	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation Delay An to Bn or Bn to An	1	1.5 1.5	7.0 7.0	1.5 1.5	8.0 8.0	ns
t_{PLH} t_{PHL}	Propagation Delay LEBA to An or LEAB to Bn	4	1.5 1.5	8.5 8.5	1.5 1.5	9.5 9.5	ns
t_{PZH} t_{PZL}	Output Enable Time OEBA to An or OEAB to Bn	2	1.5 1.5	9.0 9.0	1.5 1.5	10.0 10.0	ns
t_{PHZ} t_{PLZ}	Output Disable Time OEBA to An or OEAB to Bn	2	1.5 1.5	7.0 7.0	1.5 1.5	7.5 7.5	ns
t_{PZH} t_{PZL}	Output Enable Time EBA to An or $\overline{EAB}$ to Bn	2	1.5 1.5	9.0 9.0	1.5 1.5	10.0 10.0	ns
t_{PHZ} t_{PLZ}	Output Disable Time $\overline{EBA}$ to An or $\overline{EAB}$ to Bn	2	1.5 1.5	7.0 7.0	1.5 1.5	7.5 7.5	ns
t_s	Setup Time, HIGH to LOW Data to LExx	4	2.5		2.5		ns
t_h	Hold Time, HIGH to LOW Data to LExx	4	1.5		1.5		ns
t_s	Setup Time, HIGH to LOW Data to Exx	4	2.5		2.5		ns
t_h	Hold Time, HIGH to LOW Data to Exx	4	1.5		1.5		ns
t_w	Latch Enable or Enable Pulse Width, LOW	4	3.3		3.3		ns
t_{OSHL} t_{OSLH}	Output–to–Output Skew (Note 2)			1.0 1.0			ns

1. These AC parameters are preliminary and may be modified prior to release. The maximum AC limits are design targets. Actual performance will be specified upon completion of characterization.
2. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH–to–LOW (t_{OSHL}) or LOW–to–HIGH (t_{OSLH}); parameter guaranteed by design.

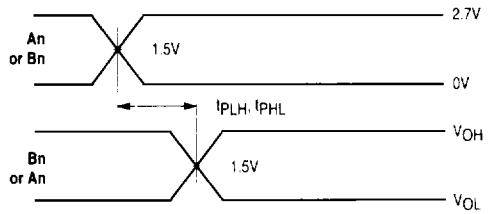
DYNAMIC SWITCHING CHARACTERISTICS

Symbol	Characteristic	Condition	T_A = +25°C			Unit
			Min	Typ	Max	
V_{OLP}	Dynamic LOW Peak Voltage[1]	V_{CC} = 3.3V, C_L = 50pF, V_{IH} = 3.3V, V_{IL} = 0V		0.8		V
V_{OLV}	Dynamic LOW Valley Voltage[1]	V_{CC} = 3.3V, C_L = 50pF, V_{IH} = 3.3V, V_{IL} = 0V		0.8		V

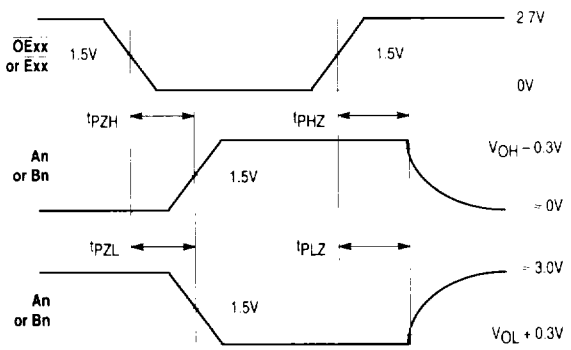
1. Number of outputs defined as "n". Measured with "n–1" outputs switching from HIGH–to–LOW or LOW–to–HIGH. The remaining output is measured in the LOW state.

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Unit
C_{PD}	Power Dissipation Capacitance	10MHz, V_{CC} = 3.3V, V_I = 0V or V_{CC}	25	pF
C_{IN}	Input Capacitance	V_{CC} = 3.3V, V_I = 0V or V_{CC}	7	pF
$C_{I/O}$	Input/Output Capacitance	V_{CC} = 3.3V, V_I = 0V or V_{CC}	8	pF

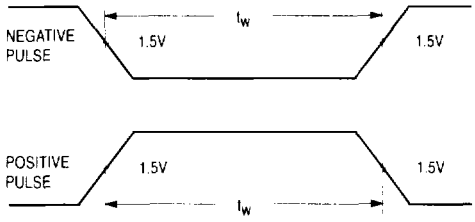


WAVEFORM 1 – A/B to B/A PROPAGATION DELAYS
$t_R = t_F$ = 2.5ns, 10% to 90%; f = 1MHz; t_W = 500ns

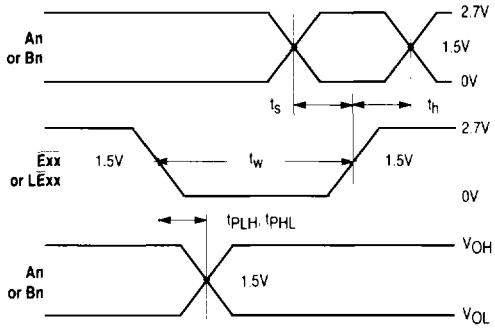


WAVEFORM 2 – $\overline{OE}$xx/$\overline{E}$xx to A or B OUTPUT ENABLE AND DISABLE TIMES
$t_R = t_F$ = 2.5ns, 10% to 90%; f = 1MHz; t_W = 500ns

Figure 1. AC Waveforms

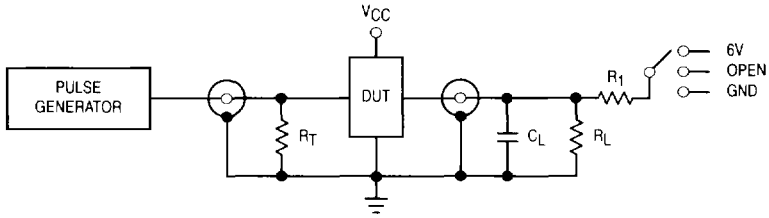


WAVEFORM 3 – INPUT PULSE DEFINITION
$t_R = t_F$ = 2.5ns, 10% to 90% of 0V to 2.7V



WAVEFORM 4 – Enable to A or B PROPAGATION DELAYS, Enable MINIMUM PULSE WIDTH, A or B to Enable SETUP AND HOLD TIMES
$t_R = t_F$ = 2.5ns, 10% to 90%; f = 1MHz; t_W = 500ns except when noted

Figure 2. AC Waveforms (continued)



TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V
Open Collector/Drain t_{PLH} and t_{PHL}	6V
t_{PZH}, t_{PHZ}	GND

C_L = 50pF or equivalent (Includes jig and probe capacitance)
$R_L = R_1$ = 500Ω or equivalent
$R_T = Z_{OUT}$ of pulse generator (typically 50Ω)

Figure 3. Test Circuit